NSN 5961-00-081-9001

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Inclosure Materia	ıl:

Metal

Overall Length:

0.230 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.310 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

500.00 milliamperes collector current, dc

Power Rating Per Characteristic:

800.0 milliwatts collector power dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Test Data Document:

03640-6020551 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0